

Product Description

The PE4273 RF Switch is designed for the TV tuner. PCTV, set top box, DTV, DVR and general broadband applications. This device offers industry leading broadband linearity, 1.5 kV ESD tolerance and a simple CMOS interface. It offers a simple alternative solution to pin diode and mechanical relay switches.

The PE4273 SPDT Broadband RF Switch is manufactured on Peregrine's UltraCMOS® process, a patented variation of silicon-on-insulator (SOI) technology on a sapphire substrate, offering the performance of GaAs with the economy and integration of conventional CMOS.

Product Specification

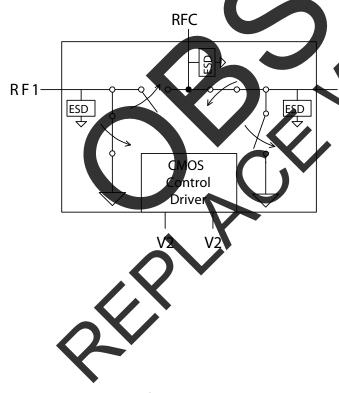
PE4273

SPDT Broadband UltraCMOS® 5 - 3000 MHz RF Switch

Features

- Single-pin or complementary CMOS logic control inputs
- High ESD tolerance of 1.5 kV
- Low insertion loss
 - 0.50 dB at 1000 MHz
 - 5 dB at 2000 MHz
- lêu.
 - 34.5 dB at 1000 MHz
 - 25 dB at 2000 MHz
- Typical input 1 dB com n point of 32 dBm
- Package type: 6-1

Figure 1. Functional Diagram



ure 2. Package Type 6-lead SC-70



Table 1. Electrical Specifications @ +25°C, V_{DD} = 3V (Z_S = Z_L = $75~\Omega$)

Parameter	Conditions	Min	Typical	Max	Units
Operation Frequency	5 - 3000 MHz	5		3000	MHz
Insertion Loss	1000 MHz 2000 MHz		0.50 0.65	0.60 0.75	dB dB
Isolation (RFC - RF1/RF2)	1000 MHz 2000 MHz	32.5 23	34.5 25		dB dB
Isolation (RF1 - RF2)	1000 MHz 2000 MHz	38.5 26	40.5 28		dB dB
Return Loss	1000 MHz 2000 MHz		18.5 14		dB dB
'ON' Switching Time 2	50% CTRL to 0.1 dB of final value, 1 GHz		0.725	1.5	μs
'OFF' Switching Time 2	50% CTRL to 25 dB isolation, 1 GHz		0.625	1.3	μѕ
Video Feedthrough 1,2			< 2	• (mV_{pp}
Input 1 dB Compression ²	5 MHz 1000 MHz	28 30	29 32		dBm dBm
Input IP3 ²	5 MHz, 19 dBm input power 1000 MHz, 19 dBm input power	X	54 53	0:-	dBm dBm

1. Measured with a 1 ns risetime, 0/3 V pulse and 500 MHz band 2. Measured in a 50 Ω system Notes:





Figure 3. Pin Configuration (Top View)

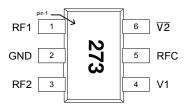


Table 2. Pin Descriptions

Pin No.	Pin Name	Description
1	RF1	RF Port1 ¹
2	GND	Ground connection. Traces should be physically short and connected to ground plane for best performance.
3	RF2	RF Port2 ¹
4	V1	Switch control input, CMOS logic level.
5	RFC	RF Common ¹
6	V2	This pin supports two interface options: Single-pin control mode. A nominal 3-volt supply connection is required. Complementary-pin control mode. A plementary CMOS control signal to V1 is supplied to this pin.

Note: 1. All RF pins must be DC blocked with an external se capacitor or held at 0 VDC

Table 3. DC Electrical Specific

Parameter	Min	Тур	Max	Units
V _{DD} Power Supply Voltage	2.7	3.0	3.3	٧
I _{DD} Power Supply Current (V1 = 3V, V2= 3V)	X	8	50	μА
Control Voltage High	0.7x V _{DD}			V
Control Voltage Low			0,3x V _{D0}	V

Table 4. Absolute Maximum Ratings

Symbol	Parameter/Conditions	Min	Max	Units
V_{DD}	Power supply voltage	-0.3	4.0	٧
VI	Voltage on any input	-0.3	V _{DD} + 0.3	٧
T _{ST}	Storage temperature range	-65	150	°C
T _{OP}	Operating temperature range	40	85	°C
P _{IN}	Input power (50 Ω) 100 - 3000 MHz 5 - 100 MNz		+34 +32	dBm dBm
V _{ESD}	ESD Voltage (NBM, ML_STD 883 Method 3015.7)		1500	V
	ESD Voltage (MM, JEDEC, JESD22-A114-B)		100	V

Exceeding these values listed in the may cause permanent dev i**c**e damage. Eunctional operation should be restricted to the its in the DC Electrical Specifications table. Exposure to absolute maximum ratings for extended periods may affect device reliability.

Latch-Up Avoidance

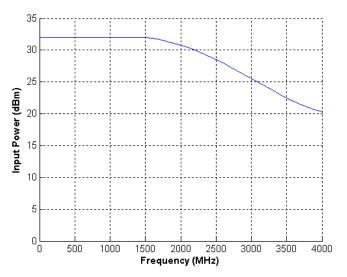
Unlike conventional CMOS devices, UltraCMOS® levices are immune to latch-up.

Electrostatic Discharge (ESD) Precautions

When handling this UltraCMOS® device, observe the same precautions that you would use with other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 4.



Figure 4. Maximum Operating Input Power¹



Note: 1. Operating within DC limits (Table 3)

Table 5. Single-pin Control Logic Truth Table

Control Voltages	Signal Path
Pin 6 (V2) = V_{DD} Pin 4 (V1) = High	RFC to RF1
Pin 6 (V2) = V _{DD} Pin 4 (V1) = Low	RFC to RF2

Table 6. Complementary-pin Control Logi **Truth Table**

Cont	rol Voltages	Si	ignal Path
	(V2) = Low (V1) = High		RC to RF1
Pin 6 Pin 4	(V2) = High (V1) = Low		RFC to RF2

Control Logic Input

The PE4273 is a versatile RF CMOS switch that supports two operating control modes; single-pin control mode and complementary-pin control mode.

Single-pin control mode enables the switch to operate with a single control pin (pin 4) supporting a +3-volt CMOS logic input, and requires a dedicated +3-volt power supply connection (pin 6). This mode of operation reduces the number of control lines required and simplifies the switch control interface typically derived from a CMOS µProcessor I/O port.

Complementary-pin control mode all switch to operate using complement pins V1 and V2 (pir that can be directly driven by +3-volt CMOS logic or a suitable port. Th operate in positive control voltage mode within the E4273 operating limit



Evaluation Kit

The SPDT Switch Evaluation Kit board was designed to ease customer evaluation of the PE4273 SPDT switch. The RF common port is connected through a 75 Ω transmission line to the bottom F connector, J2. Port 1 and Port 2 are connected through 75 Ω transmission lines to two F connectors on either side of the board, J3 and J1. A through transmission line connects F connectors J4 and J5. This transmission line can be used to estimate the loss of the PCB over the environmental conditions being evaluated.

The board is constructed of a two metal layer FR4 material with a total thickness of 0.031". The bottom layer provides ground for the RF transmission lines. The transmission lines were designed using a coplanar waveguide with ground plane model using a trace width of 0.021", trace gaps of 0.030", dielectric thickness of 0.028", copper thickness of 0.0021" and ϵ_r of 4.3.

J6 and J7 provide a means for controlling the DC inputs to the device. The lower left header (J6) connected to the device V1 input. The lower r header (J7) is connected to the device V2 input Series resistors (R1 and R2) are provided to red the package resonance between RF and BC line. Footprints for decoupling capacitors (100 pF) are provided on both V1 and V2 traces. It is t responsibility of the customer to determine prope supply decoupling for their design application, Removing these components from the evaluation board has not been shown to d egrade performance.

Figure 5. Evaluation Board Layouts

Peregrine Specification 101/0245

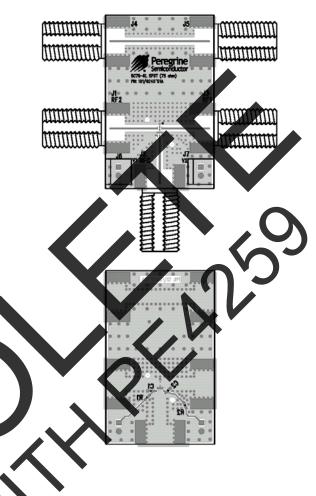




Figure 6. Evaluation Board Schematic

Peregrine Specification 102/0311

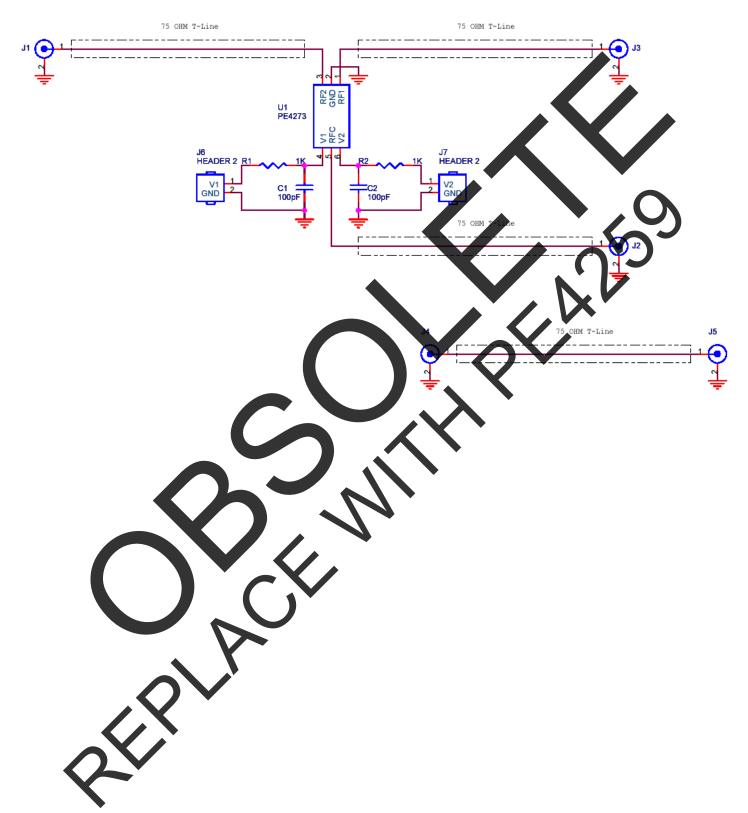




Figure 7. Isolation: RF1 - RF2 @ 25°C

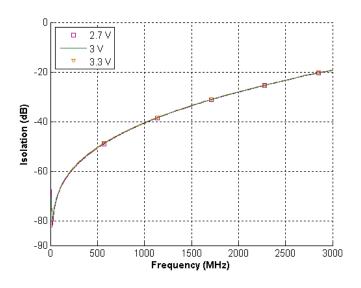


Figure 8. Isolation: RF1 - RF2 @ 3.0V

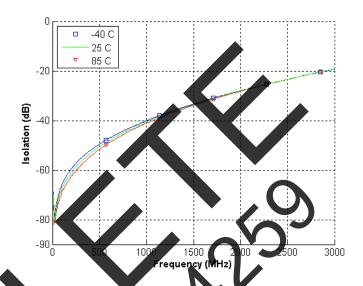
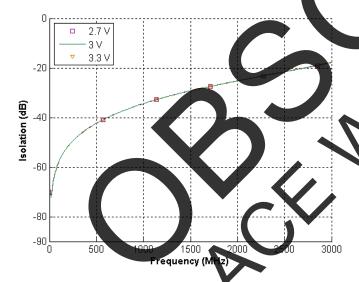


Figure 9. Isolation: RFC - RF1/RF2 @ 25°



RF1/RF2 @ 3.0V

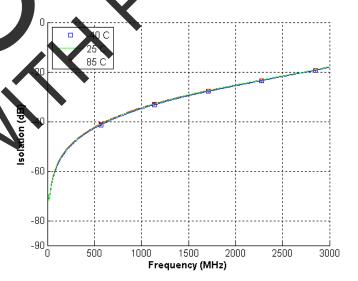




Figure 11. Insertion Loss @ 25°C

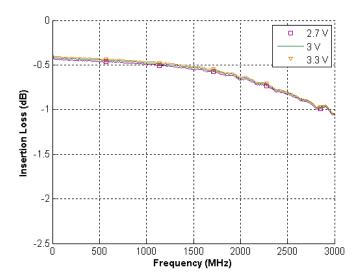


Figure 12. Insertion Loss @ 3.0V

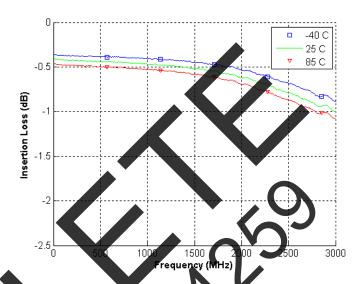
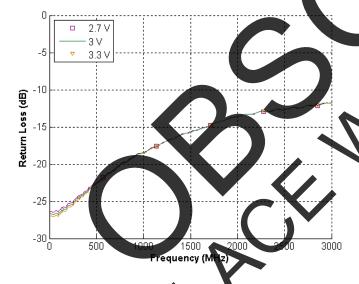


Figure 13. Return Loss: RF1/RF2 @ 25°C



RF1/RF2 @ 3.0V

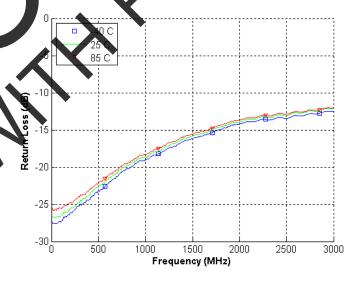




Figure 15. Return Loss: RFC/RF1 @ 25°C

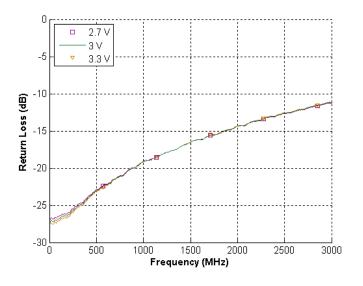


Figure 16. Return Loss: RFC/RF1 @ 3.0V

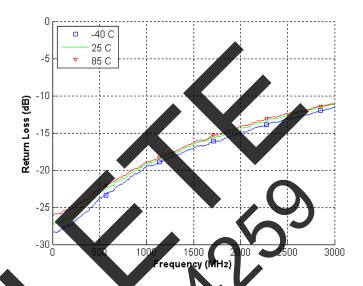
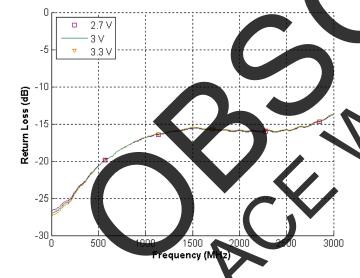


Figure 17. Return Loss: RFC/RF2 @ 25°C



RFC/RF2 @ 3.0V

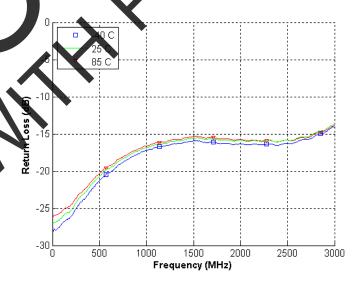




Figure 19. Input 1 dB Compression and IIP3

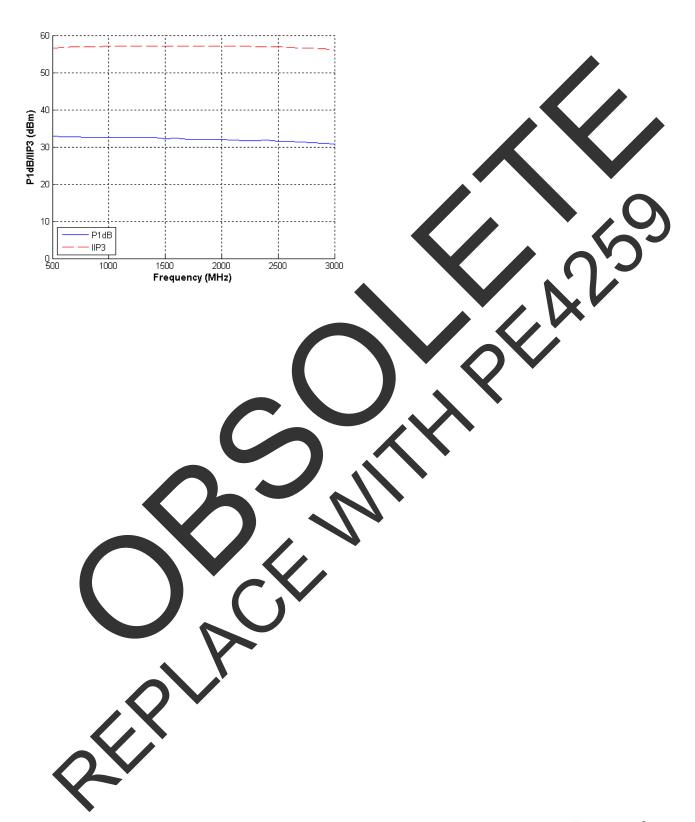
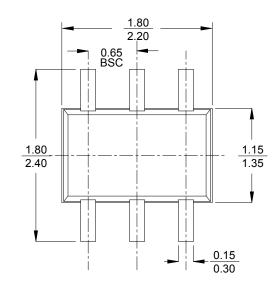
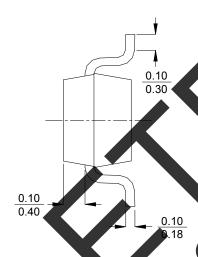
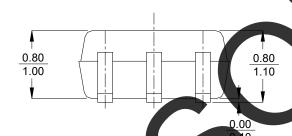




Figure 20. Package Drawing 6-lead SC-70





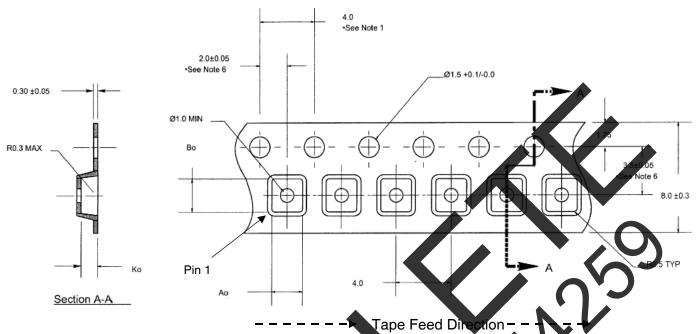


- NOTE:

 1. ALL DIMENSION
 MILLIMETER
 DIMENSIONS AF

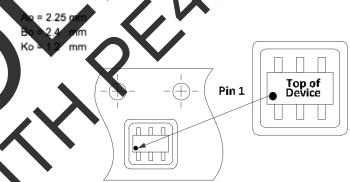


Figure 21. Tape and Reel Specifications



Notes:

- 1. 10 sprocket hole pitch cumulative tolerance ±.02.
- Camber not to exceed 1mm in 100mm.
- Material: Black Conductive Advantek Polystyrene.
- Ao and Bo measured on a plane 0.3mm above
 the bottom of the pocket
- Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole



Device Orientation in Tape

Table 7. Ordering Information

Order Code	Part Marking	Description	Package	Shipping Method
4273-00	PE4273-EK	PE4273-16SC70-EK	Evaluation Kit	1 / Box
4273-51	273	PE4273G-06SC70-7680A	Green 6-lead SC-70	7680 units / Canister
4273-52	273	PE 273 a-06SC70-3000C	Green 6-lead SC-70	3000 units / T&R

Sales Contact and Information

For sales and contact information please visit www.psemi.com.

Advance Information: The product is in a Nomative or design stage. The datasheet contains design target specifications for product development Specifications and features may change in any manner without notice. Preliminary Specification: The datasheet contains preliminary data. Additional data may be added at a later date. Peregrine researche right to change specifications at any time without notice in order to supply the best possible product. Product specification of the datasheet contains final data. In the event Peregrine decides to change the specifications decides to change the specification decides the

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